EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S21	26526	(gate NEAR4 negative)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/12 10:15
S22	1271	electrons NEAR4 photodiode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/12 10:15
S23	2	S21 SAME S22	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/12 10:09
S24	30909	(gate NEAR4 positive)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/12 10:15
S25	845	holes NEAR4 photodiode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/12 10:15
S26	3	S24 SAME S25	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/12 10:21
S27	41	gate SAME negative SAME electrons Same photodiode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/12 11:06
S28	26	transfer SAME negative SAME electrons Same photodiode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/12 11:06

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S29	299	towler.in.	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/08 10:41
S30	15474	micron.as.	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/08 10:39
S31	6	S29 AND camera	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/08 10:42
S32	51	348/291	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/08 11:01
S33	1551	electron NEAR5 (photodiode OR photocell)	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/08 11:07
S34	57136	(transistor OR gate) NEAR5 negative	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/08 11:07
S35	75	S33 AND S34	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/08 11:03
S36	12	S33 SAME S34	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/08 11:03
S37	2548	(positive OR holes) NEAR5 (photodiode OR photocell)	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/08 11:21
S38	66234	(transistor OR gate) NEAR5 positive	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/08 11:21
S39	134	S37 SAME S38	US-PGPUB; USPAT; USOCR	OR	ON	2006/02/08 11:08
S40	102	(positive OR holes) NEAR5 (photodiode OR photocell)	JPO	OR	ON	2006/02/08 11:21
S41	2381	(transistor OR gate) NEAR5 positive	JPO	OR	ON	2006/02/08 11:22
S42	3	S40 AND S41	JPO	OR	ON	2006/02/08 11:22
S43	3	(("5345357") or ("4688098") or ("5900623")).PN.	USPAT; USOCR	OR	OFF	2006/02/10 06:59
S44	654	(voltage$3) SAME (accumulat$3 OR stor$3 OR integrat$4) SAME charg$3 SAME (CMOS OR CCD) SAME diod$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/10 07:00

S45	34	S44 SAME (positi$4 ADJ1 voltage$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 08:29
S46	106	S44 SAME (increas$3 OR decreas$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/10 08:01
S47	1438	(dark ADJ (current OR electron OR charge)) SAME diod$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/10 10:25
S48	365	S47 AND $2MOS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/10 10:27
S49	101	(S47 SAME transistor) AND $2MOS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/10 10:27
S50	30	transistor SAME (positi$4 ADJ1 voltage$3) SAME (bloom$4 OR overflow$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 08:59
S51	145	overflow$4 SAME (depth NEAR6 direction)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 09:06
S52	11	S51 SAME photodiode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 09:00

S53	105	(vertical NEAR3 overflow) SAME photodiode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 09:07
S54	1	("4688098").PN.	USPAT; USOCR	OR	OFF	2006/02/16 08:09